# BLF178XR; BLF178XRS

## Power LDMOS transistor

**AMPLEON** 

Rev. 5 — 1 September 2015

Product data sheet

### 1. Product profile

#### 1.1 General description

A 1400 W extremely rugged LDMOS power transistor for broadcast and industrial applications in the HF to 128 MHz band.

Table 1. Application information

Test signal	f	V <sub>DS</sub>	PL	Gp	η <sub>D</sub>
	(MHz)	(V)	(W)	(dB)	(%)
CW	108	50	1200	23	80
pulsed RF	108	50	1400	28	72

#### 1.2 Features and benefits

- Typical pulsed performance at frequency of 108 MHz, a supply voltage of 50 V and an  $I_{Dq}$  of 40 mA, a  $t_p$  of 100 μs with  $\delta$  of 20 %:
  - ◆ Output power = 1400 W
  - ◆ Power gain = 28 dB
  - ◆ Efficiency = 72 %
- Easy power control
- Integrated ESD protection
- Excellent ruggedness
- High efficiency
- Excellent thermal stability
- Designed for broadband operation (HF to 128 MHz)
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

#### 1.3 Applications

- Industrial, scientific and medical applications
- Broadcast transmitter applications

## 2. Pinning information

Table 2. Pinning

	9		
Pin	Description	Simplified outline	Graphic symbol
BLF178XF	R (SOT539A)		
1	drain1		
2	drain2	1 2	1 . 🖵
3	gate1	2 5	5 3
4	gate2	3 4	5
5	source	[1]	4
			' <u></u>
			2 sym117

BLF178XF	RS (SOT539B)			
1	drain1			
2	drain2		1 2	1 
3	gate1		5	, H
4	gate2		3 4	3 - 5
5	source	[1]		4

<sup>[1]</sup> Connected to flange.

## 3. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Version			
BLF178XR	-	flanged balanced LDMOST ceramic package; 2 mounting holes; 4 leads	SOT539A		
BLF178XRS	-	earless flanged balanced LDMOST ceramic package; 4 leads	SOT539B		

## 4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DS}$	drain-source voltage		-	110	V
$V_{GS}$	gate-source voltage		-6	+11	V
T <sub>stg</sub>	storage temperature		-65	+150	°C
T <sub>j</sub>	junction temperature		-	200	°C

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### 5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions		Тур	Unit
$R_{th(j-c)}$	thermal resistance from junction to case	T <sub>j</sub> = 150 °C	[1][2]	0.11	K/W
$Z_{\text{th(j-c)}}$	transient thermal impedance from junction to case	$T_j$ = 150 °C; $t_p$ = 100 $\mu$ s; $\delta$ = 20 %	[3]	0.033	K/W

- [1]  $T_i$  is the junction temperature.
- [2] Rth(j-c) is measured under RF conditions.
- [3] See Figure 1.

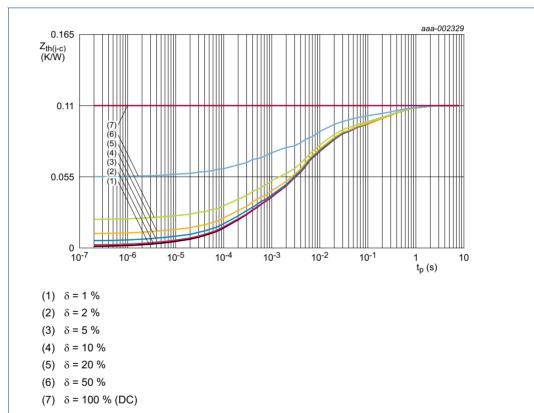


Fig 1. Transient thermal impedance from junction to case as a function of pulse duration

### 6. Characteristics

#### Table 6. DC characteristics

 $T_i = 25$  °C; per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 5.5 \text{ mA}$	110	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$V_{DS}$ = 10 V; $I_{D}$ = 550 mA	1.25	1.7	2.25	V
$V_{GSq}$	gate-source quiescent voltage	$V_{DS}$ = 50 V; $I_{D}$ = 20 mA	8.0	1.3	1.8	V
$I_{DSS}$	drain leakage current	$V_{GS}$ = 0 V; $V_{DS}$ = 50 V	-	-	2.8	μΑ
I <sub>DSX</sub>	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 V;$ $V_{DS} = 10 V$	-	77	-	Α
I <sub>GSS</sub>	gate leakage current	$V_{GS} = 11 \text{ V}; V_{DS} = 0 \text{ V}$	-	-	280	nΑ
R <sub>DS(on)</sub>	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 19.25 \text{ A}$	-	0.07	-	Ω

#### Table 7. AC characteristics

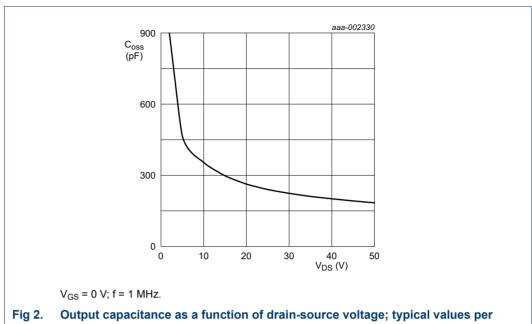
 $T_i = 25$  °C; per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
C <sub>rs</sub>	feedback capacitance	$V_{GS}$ = 0 V; $V_{DS}$ = 50 V; f = 1 MHz	-	5.5	-	pF
C <sub>iss</sub>	input capacitance	$V_{GS}$ = 0 V; $V_{DS}$ = 50 V; f = 1 MHz	-	414	-	pF
C <sub>oss</sub>	output capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V}; f = 1 \text{ MHz}$	-	184	-	pF

#### Table 8. RF characteristics

Test signal: pulsed RF;  $t_p$  = 100  $\mu$ s;  $\delta$  = 20 %; f = 108 MHz; RF performance at  $V_{DS}$  = 50 V;  $I_{Dq}$  = 40 mA;  $T_{case}$  = 25 °C; unless otherwise specified; in a class-AB production test circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Gp	power gain	$P_{L} = 1400 \text{ W}$	27	28	-	dB
RLin	input return loss	P <sub>L</sub> = 1400 W	-	-15	-11	dB
$\eta_{D}$	drain efficiency	P <sub>L</sub> = 1400 W	68	72	-	%



## section

### 7. Test information

#### 7.1 Ruggedness in class-AB operation

The BLF178XR and BLF178XRS are capable of withstanding a load mismatch corresponding to VSWR > 65 : 1 through all phases under the following conditions:  $V_{DS} = 50 \text{ V}$ ;  $I_{Dq} = 40 \text{ mA}$ ;  $P_L = 1400 \text{ W}$  pulsed; f = 108 MHz.

#### 7.2 Impedance information

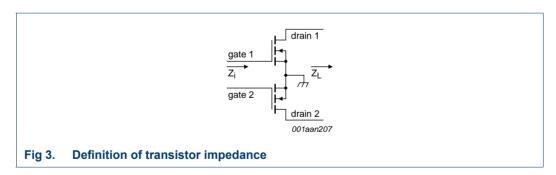
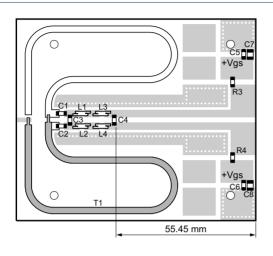


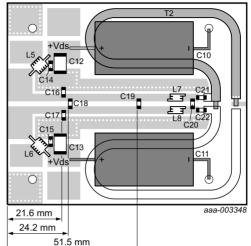
Table 9. Typical push-pull impedance

Simulated  $Z_i$  and  $Z_L$  device impedance; impedance info at  $V_{DS} = 50 \text{ V}$  and  $P_L = 1400 \text{ W}$ .

f	$Z_i$	Z <sub>L</sub>
(MHz)	$(\Omega)$	(Ω)
108	2.35 – j6.06	2.78 + j0.48

#### 7.3 Test circuit





Printed-Circuit Board (PCB): RF 35;  $\epsilon_r$  = 3.5; thickness = 0.765 mm; thickness copper plating = 35  $\mu$ m. See Table 10 for a list of components.

Fig 4. Component layout for class-AB production test circuit

**Table 10.** List of components For test circuit see Figure 4.

Value Remarks Component **Description** [1] C1, C2, C5, C6, C14, multilayer ceramic chip capacitor 1 nF C15, C21, C22 [1] C3 82 pF multilayer ceramic chip capacitor C4 [1] 240 pF multilayer ceramic chip capacitor C7, C8 multilayer ceramic chip capacitor 4.7 μF; 50 V C10, C11 electrolytic capacitor 2200 μF: 63 V C12, C13 4.7 μF; 100 V multilayer ceramic chip capacitor C16, C17 multilayer ceramic chip capacitor 120 pF [1] [1] C18 multilayer ceramic chip capacitor 82 pF [1] C19 multilayer ceramic chip capacitor 110 pF [1] C20 multilayer ceramic chip capacitor 56 pF L1, L2, L3, L4 1.5 turn 0.8 mm copper wire D = 3 mm: length = 2 mm L5, L6 5 turn 0.8 mm copper wire D = 3 mm; length = 4.5 mmL7, L8 2.5 turn 0.8 mm copper wire D = 3 mm; length = 3 mmR3, R4 SMD resistor 1206  $9.1 \Omega$ T1 25 Ω; 160 mm UT-090C-25 semi rigid coax T2 UT-141C-25 semi rigid coax 25 Ω; 160 mm

<sup>[1]</sup> American Technical Ceramics type 800B or capacitor of same quality.

#### 7.4 Graphical data

The following figures are measured in a class-AB production test circuit.

#### 7.4.1 1-Tone CW pulsed

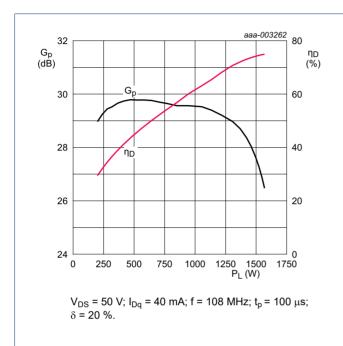
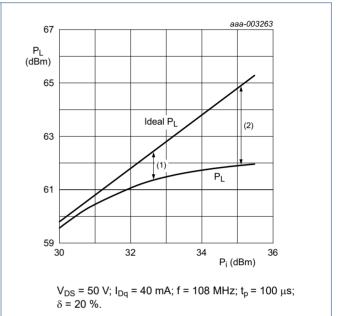


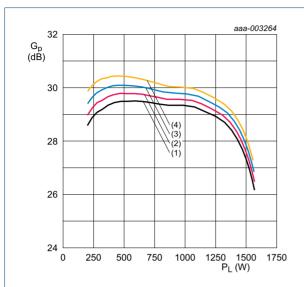
Fig 5. Power gain and drain efficiency as function of output power; typical values



(1)  $P_{L(1dB)} = 61.3 \text{ dBm } (1350 \text{ W})$ 

(2)  $P_{L(3dB)} = 61.9 \text{ dBm } (1550 \text{ W})$ 

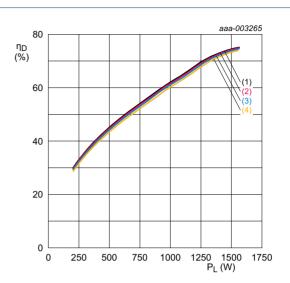
Fig 6. Output power as a function of input power; typical values



 $V_{DS}$  = 50 V; f = 108 MHz;  $t_p$  = 100  $\mu$ s;  $\delta$  = 20 %.

- (1)  $I_{Dq} = 20 \text{ mA}$
- (2)  $I_{Dq} = 40 \text{ mA}$
- (3)  $I_{Dq} = 80 \text{ mA}$
- (4)  $I_{Dq} = 160 \text{ mA}$

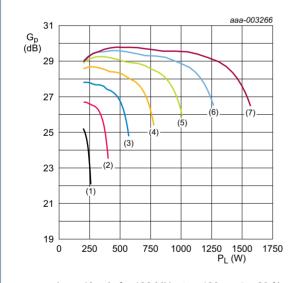
Fig 7. Power gain as a function of output power; typical values



 $V_{DS} = 50 \text{ V}$ ; f = 108 MHz;  $t_p = 100 \text{ }\mu\text{s}$ ;  $\delta = 20 \text{ }\%$ .

- (1)  $I_{Dq} = 20 \text{ mA}$
- (2)  $I_{Dq} = 40 \text{ mA}$
- (3)  $I_{Dq} = 80 \text{ mA}$
- (4)  $I_{Dq} = 160 \text{ mA}$

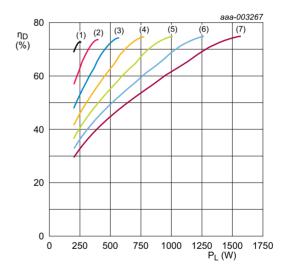
Fig 8. Drain efficiency as a function of output power; typical values



 $I_{Dq}$  = 40 mA; f = 108 MHz;  $t_p$  = 100  $\mu$ s;  $\delta$  = 20 %.

- (1)  $V_{DS} = 20 \text{ V}$
- (2)  $V_{DS} = 25 V$
- (3)  $V_{DS} = 30 \text{ V}$
- (4)  $V_{DS} = 35 \text{ V}$
- (5)  $V_{DS} = 40 \text{ V}$
- (6)  $V_{DS} = 45 \text{ V}$
- (7)  $V_{DS} = 50 \text{ V}$

Fig 9. Power gain as a function of output power; typical values



 $I_{Dq}$  = 40 mA; f = 108 MHz;  $t_p$  = 100  $\mu$ s;  $\delta$  = 20 %.

- (1)  $V_{DS} = 20 \text{ V}$
- (2)  $V_{DS} = 25 V$
- (3)  $V_{DS} = 30 \text{ V}$
- (4)  $V_{DS} = 35 V$
- (5)  $V_{DS} = 40 \text{ V}$
- (6)  $V_{DS} = 45 V$
- (7)  $V_{DS} = 50 \text{ V}$

Fig 10. Drain efficiency as a function of output power; typical values

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## 8. Package outline

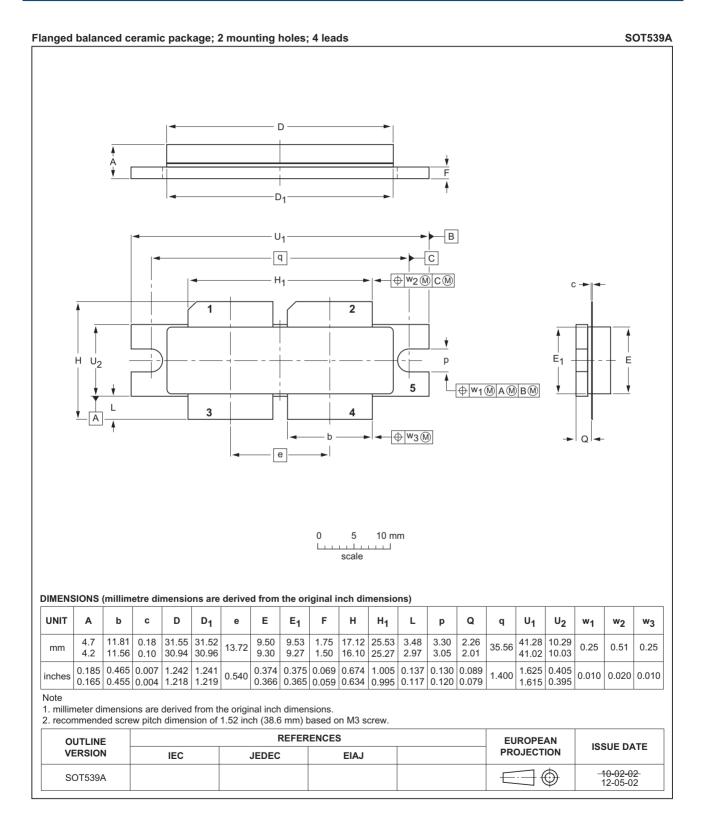


Fig 11. Package outline SOT539A

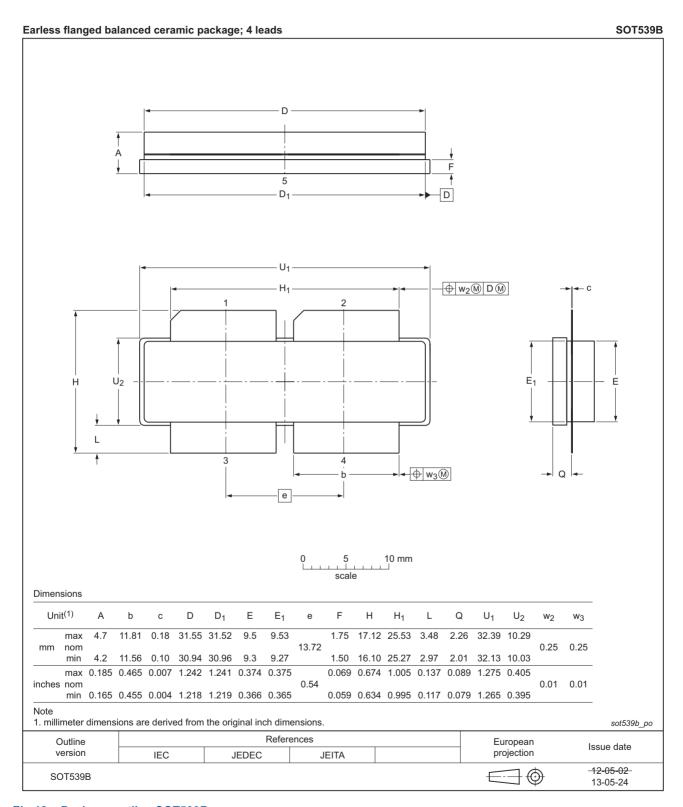


Fig 12. Package outline SOT539B

## 9. Handling information

#### CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

## 10. Abbreviations

Table 11. Abbreviations

Acronym	Description
CW	Continuous Wave
ESD	ElectroStatic Discharge
HF	High Frequency
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
LDMOST	Laterally Diffused Metal-Oxide Semiconductor Transistor
SMD	Surface Mounted Device
VSWR	Voltage Standing-Wave Ratio

## 11. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
BLF178XR_BLF178XRS#5	20150901	Product data sheet	-	BLF178XR_BLF178XRS v.4			
Modifications:		The format of this document has been redesigned to comply with the new identity guidelines of Ampleon.					
	<ul> <li>Legal texts</li> </ul>	have been adapted to the	ne new company na	ame where appropriate.			
BLF178XR_BLF178XRS v.4	<tbd></tbd>	Product data sheet	-	BLF178XR_BLF178XRS v.3			
BLF178XR_BLF178XRS v.3	20120625	Product data sheet	-	BLF178XR_BLF178XRS v.2			
BLF178XR_BLF178XRS v.2	20120515	Preliminary data sheet	-	BLF178XR_BLF178XRS v.1			
BLF178XR_BLF178XRS v.1	20120130	Objective data sheet	-	-			

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Document status[1][2]	Product status[3]	Definition
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**Power LDMOS transistor** 

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